



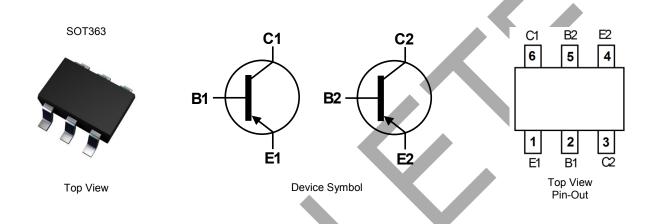
25V DUAL PNP SMALL SIGNAL TRANSISTOR IN SOT363

Features

- Ultra-Small Surface Mount Package
- **Epitaxial Planar Die Construction**
- Ideal for Medium Power Amplification and Switching
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT363 •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)



Ordering Information (Note 4)

Part number	Status	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMDT4126-7-F	Obsolete	AEC-Q101	K2B	7	8	3,000

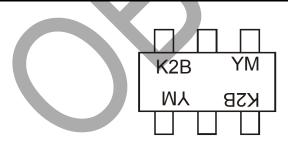
Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K2B = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: D = 2016) M or \overline{M} = Month (ex: 9 = September)

Year	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027
Code	D	E	F	G	Н		J	К	L	М	N	0
	_		-	-		-	-					-
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-25	V
Emitter-Base Voltage	V _{EBO}	-4.0	V
Collector Current	lc	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	D °

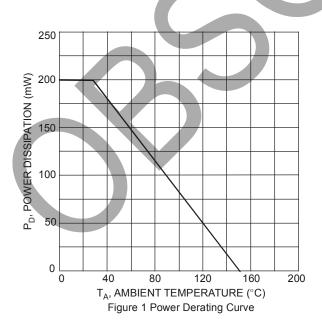
ESD Ratings (Note 6)

-				
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For the device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

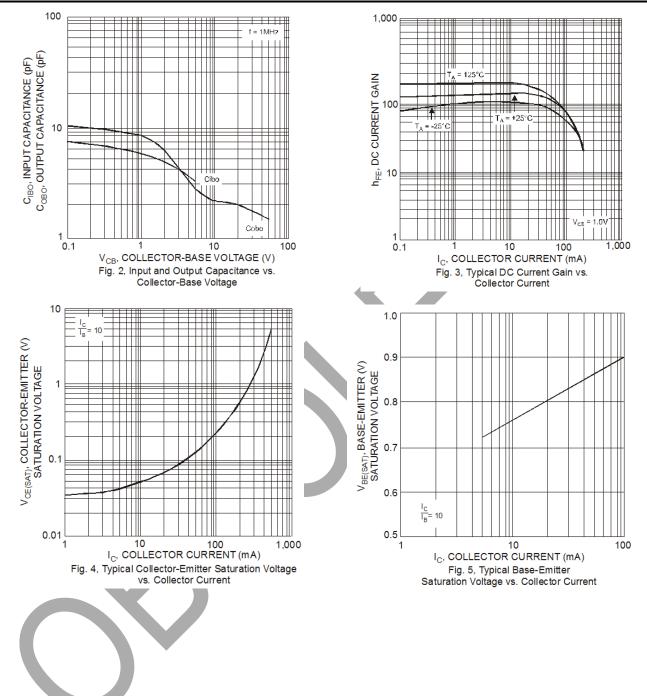
Oh ann at a di a ti a	O make at	M	T		11	To a to Q a se all'the se
Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition
OFF CHARACTERISTICS				1	1	
Collector-Base Breakdown Voltage	BV _{CBO}	-25			V	$I_{\rm C} = -10\mu A$, $I_{\rm B} = 0$
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	-25	_		V	I _C = -10mA, I _B = 0
Emitter-Base Breakdown Voltage	BV _{EBO}	-4.0	—	_	V	$I_{E} = -10\mu A$, $I_{C} = 0$
Collector Cutoff Current	I _{CBO}			-50	nA	V _{CB} = -20V, I _E = 0
Collector Cutoff Current	I _{EBO}	_	—	-50	nA	$V_{EB} = -3V, I_{C} = 0$
ON CHARACTERISTICS (Note 7)						
DC Current Gain	b	120	—	300		I _C = -2mA, V _{CE} = -1V
	h _{FE}	60	—			1 _C = -50mA, V _{CE} = -1V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	—	-0.4	V	I _C = -50mA, I _B = -5mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	—	-0.95	V	$I_{\rm C}$ = -50mA, $I_{\rm B}$ = -5mA
SMALL SIGNAL CHARACTERISTICS			•		·	
Output Capacitance	Сово	_	—	4.5	pF	$V_{CB} = -5V$, f = 1MHz, I _E = 0
Input Capacitance	C _{IBO}	_	—	10	pF	V _{EB} = -0.5V, f = 1MHz, I _C = 0
Small Signal Current Gain	h _{fe}	120	-	480	1	V _{CE} = -1V, I _C = -2mA, f = 1kHz
Current Gain Bandwidth Product	f _T	250	-		MHz	V _{CE} = -20V, I _C = -10mA, f = 100MHz
Noise Figure	NF	_		4.0	dB	$V_{CE} = -5V, I_C = -100\mu A,$ $R_S = 1k\Omega, f = 1kHz$

Note: 7. Short duration pulse test used to minimize self-heating effect.

MMDT4126 Document number: DS30160 Rev. 12 - 4



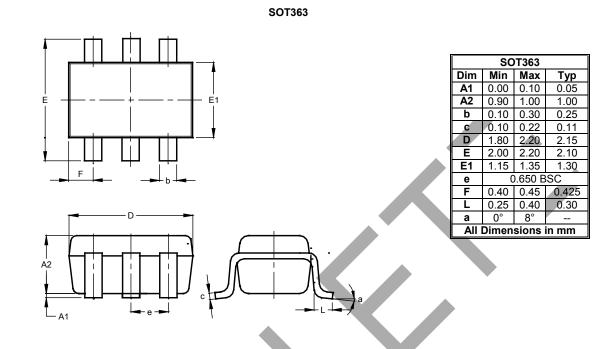
Typical Electrical Characteristics (@T_A = +25°C unless otherwise specified.)





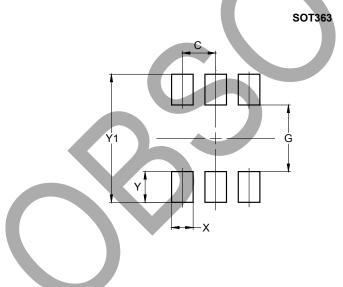
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500



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